查询"BUK7660-100A"供应商

42V PowerNet

BUK7560-100A; BUK7660-100A

TrenchMOS™ standard level FET

Rev. 01 — 22 February 2001 Product specification

1. Description

N-channel enhancement mode field-effect power transistor in a plastic package using TrenchMOS™ technology, featuring very low on-state resistance.

Product availability:

BUK7560-100A in SOT78 (TO-220AB)

BUK7660-100A in SOT404 (D^2-PAK).

2. Features

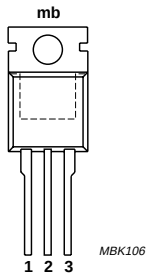
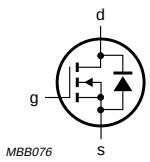
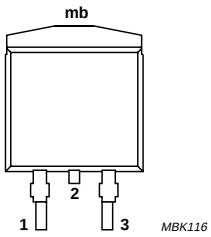
- TrenchMOS™ technology
- Q101 compliant
- 175 °C rated
- Standard level compatible.

3. Applications

- Automotive and general purpose power switching:
  - 12 V, 24 V and 42 V loads
  - Motors, lamps and solenoids.

4. Pinning information

Table 1: Pinning - SOT78 and SOT404, simplified outline and symbol

Pin	Description	Simplified outline	Symbol
1	gate (g)	 SOT78 (TO-220AB)	
2	drain (d)	 SOT404 (D^2-PAK)	
3	source (s)		
mb	mounting base; connected to drain (d)		

5. Quick reference data

Table 2: Quick reference data

Symbol	Parameter	Conditions	Typ	Max	Unit
V_{DS}	drain-source voltage (DC)		–	100	V
I_D	drain current (DC)	T_{mb} = 25 °C; V_{GS} = 10 V	–	26	A
P_{tot}	total power dissipation	T_{mb} = 25 °C	–	106	W
T_j	junction temperature		–	175	°C
R_{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 15 A			
		T_j = 25 °C	51	60	mΩ
		T_j = 175 °C	–	150	mΩ

6. Limiting values

Table 3: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage (DC)		–	100	V
V_{DGR}	drain-gate voltage (DC)	R_{GS} = 20 kΩ	–	100	V
V_{GS}	gate-source voltage (DC)		–	±20	V
I_D	drain current (DC)	T_{mb} = 25 °C; V_{GS} = 10 V; Figure 2 and 3	–	26	A
		T_{mb} = 100 °C; V_{GS} = 10 V; Figure 2	–	19	A
I_{DM}	peak drain current	T_{mb} = 25 °C; pulsed; $t_p \leq 10$ µs; Figure 3	–	106	A
P_{tot}	total power dissipation	T_{mb} = 25 °C; Figure 1	–	106	W
T_{stg}	storage temperature		–55	+175	°C
T_j	operating junction temperature		–55	+175	°C
Source-drain diode					
I_{DR}	reverse drain current (DC)	T_{mb} = 25 °C	–	26	A
I_{DRM}	pulsed reverse drain current	T_{mb} = 25 °C; pulsed; $t_p \leq 10$ µs	–	106	A
Avalanche ruggedness					
W_{DSS}	non-repetitive avalanche energy	unclamped inductive load; I_D = 20 A; $V_{DS} \leq 100$ V; V_{GS} = 10 V; R_{GS} = 50 Ω; starting T_{mb} = 25 °C	–	110	mJ

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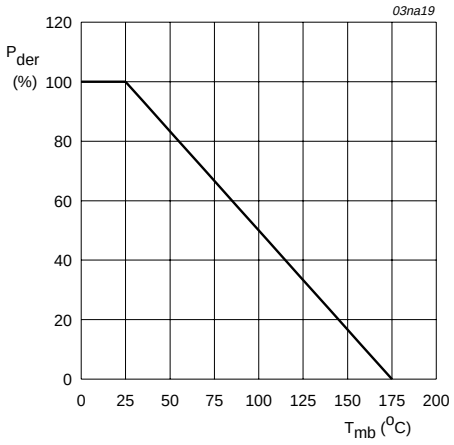
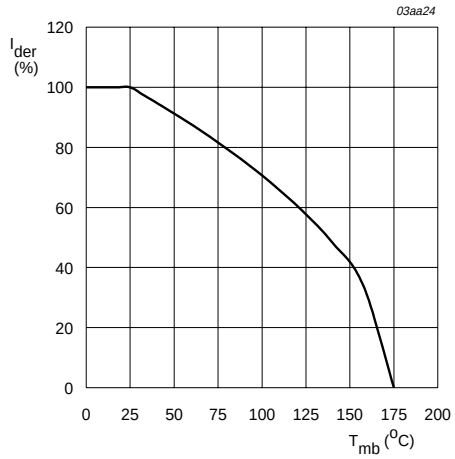


$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

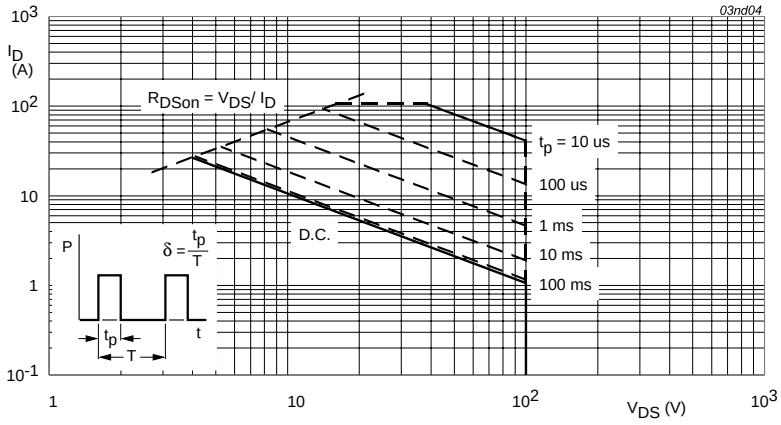
Fig 1. Normalized total power dissipation as a function of mounting base temperature.



$V_{GS} \geq 4.5$ V

$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100\%$$

Fig 2. Normalized continuous drain current as a function of mounting base temperature.



T_{mb} = 25 °C; I_{DM} single pulse.

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage.

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7. Thermal characteristics

Table 4: Thermal characteristics

Symbol	Parameter	Conditions	Value	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	vertical in still air; SOT78 package	60	K/W
		mounted on printed circuit board; minimum footprint; SOT404 package	50	K/W
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Figure 4	1.4	K/W

7.1 Transient thermal impedance

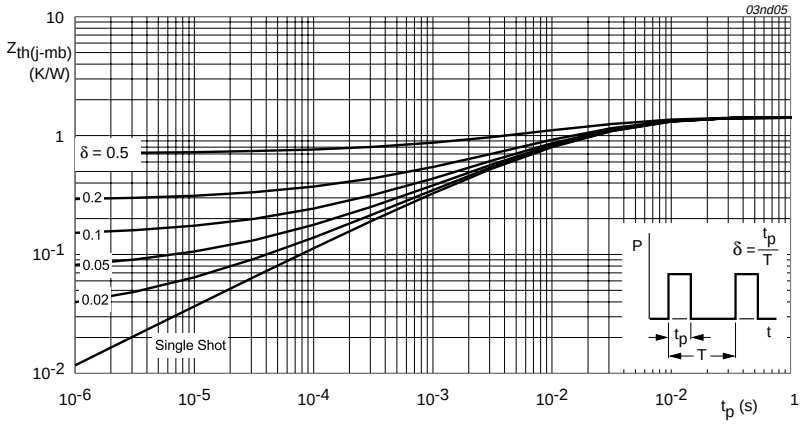

Fig 4. Transient thermal impedance from junction to mounting base as a function of pulse duration.

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8. Characteristics

Table 5: Characteristics

T_j = 25 °C unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	I_D = 0.25 mA; V_{GS} = 0 V				
		T_j = 25 °C	100	–	–	V
		T_j = –55 °C	89	–	–	V
$V_{GS(th)}$	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS}; Figure 9				
		T_j = 25 °C	2	3	4	V
		T_j = 175 °C	1	–	–	V
		T_j = –55 °C	–	–	4.4	V
I_{DSS}	drain-source leakage current	V_{DS} = 100 V; V_{GS} = 0 V				
		T_j = 25 °C	–	0.05	10	µA
		T_j = 175 °C	–	–	500	µA
I_{GSS}	gate-source leakage current	V_{GS} = ±20 V; V_{DS} = 0 V	–	2	100	nA
R_{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 15 A; Figure 7 and 8				
		T_j = 25 °C	–	51	60	mΩ
		T_j = 175 °C	–	–	150	mΩ
Dynamic characteristics						
C_{iss}	input capacitance	V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz; Figure 12	–	1030	1377	pF
C_{oss}	output capacitance		–	143	171	pF
C_{rss}	reverse transfer capacitance		–	90	120	pF
$t_{d(on)}$	turn-on delay time	V_{DD} = 30 V; R_L = 1.2 Ω; V_{GS} = 10 V; R_G = 10 Ω;	–	10	–	ns
t_r	rise time		–	45	–	ns
$t_{d(off)}$	turn-off delay time		–	31	–	ns
t_f	fall time		–	20	–	ns
L_d	internal drain inductance	from drain lead 6 mm from package to centre of die	–	4.5	–	nH
		from contact screw on mounting base to centre of die SOT78	–	3.5	–	nH
		from upper edge of drain mounting base to centre of die SOT404	–	2.5	–	nH
L_s	internal source inductance	from source lead to source bond pad	–	7.5	–	nH

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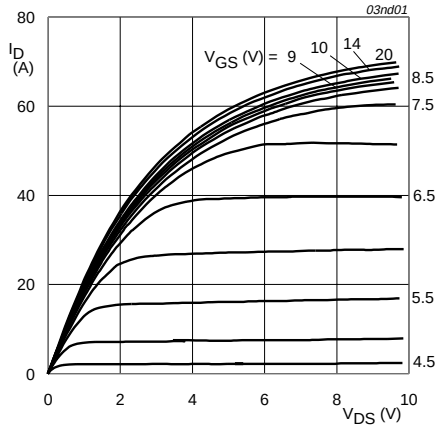
Table 5: Characteristics *...continued*

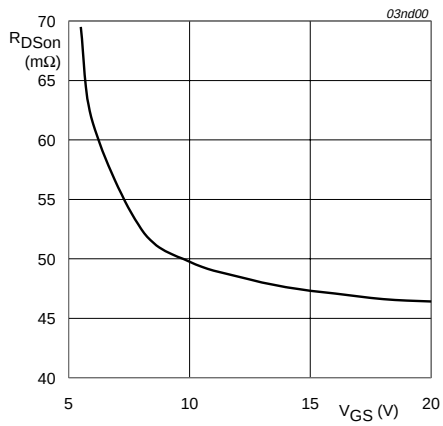
T_j = 25 °C unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Source-drain diode						
V_{SD}	source-drain (diode forward) voltage	I_S = 25 A; V_{GS} = 0 V; Figure 15	–	0.85	1.2	V
t_{rr}	reverse recovery time	I_S = 20 A; dI_S/dt = –100 A/µs V_{GS} = –10 V; V_{DS} = 30 V	–	59	–	ns
Q_r	recovered charge		–	180	–	nC



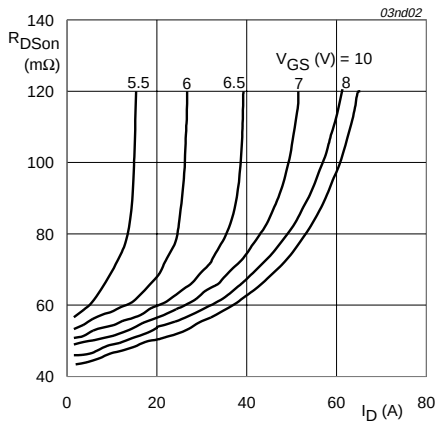
T_j = 25 °C; t_p = 300 µs

Fig 5. Output characteristics: drain current as a function of drain-source voltage; typical values.



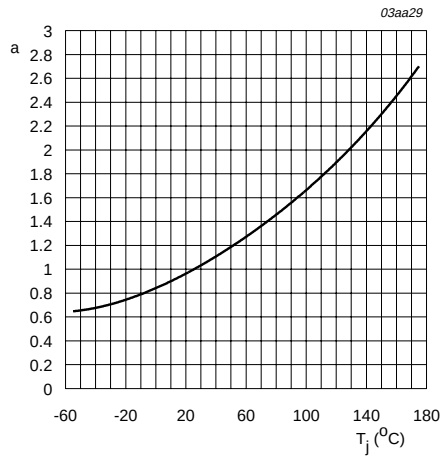
T_j = 25 °C; I_D = 10 A

Fig 6. Drain-source on-state resistance as a function of gate-source voltage; typical values.



T_j = 25 °C

Fig 7. Drain-source on-state resistance as a function of drain current; typical values.



$$a = \frac{R_{DSon}}{R_{DSon(25°C)}}$$

Fig 8. Normalized drain-source on-state resistance factor as a function of junction temperature.

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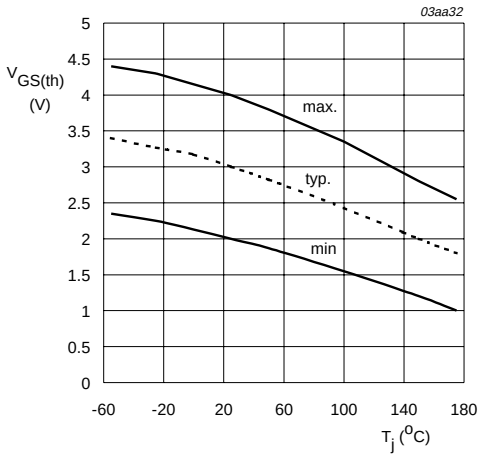
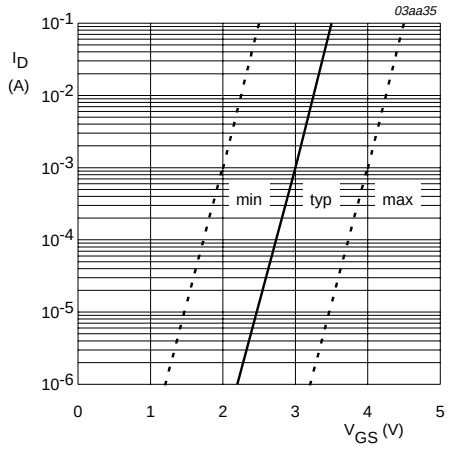


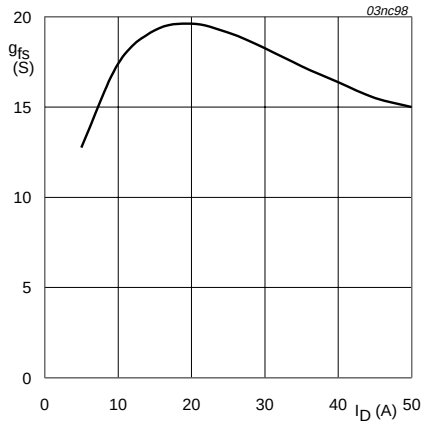
I_D = 1 mA; V_{DS} = V_{GS}

Fig 9. Gate-source threshold voltage as a function of junction temperature.



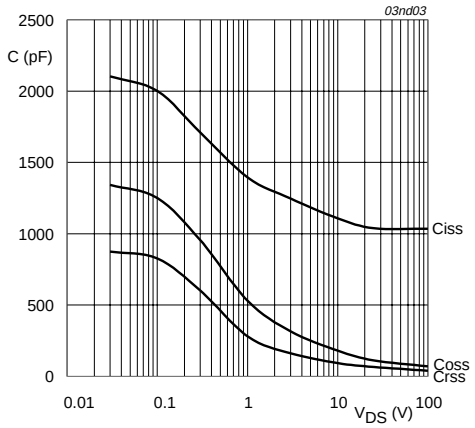
T_j = 25 °C; V_{DS} = V_{GS}

Fig 10. Sub-threshold drain current as a function of gate-source voltage.



T_j = 25 °C; V_{DS} = 25 V

Fig 11. Forward transconductance as a function of drain current; typical values.



V_{GS} = 0 V; f = 1 MHz

Fig 12. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values.

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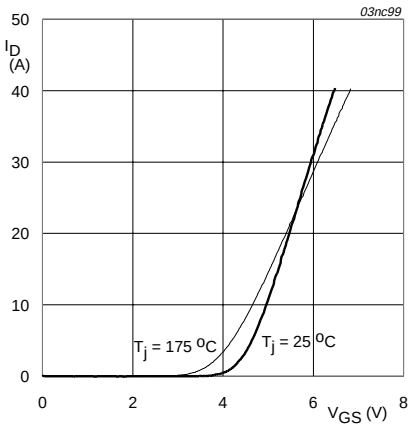
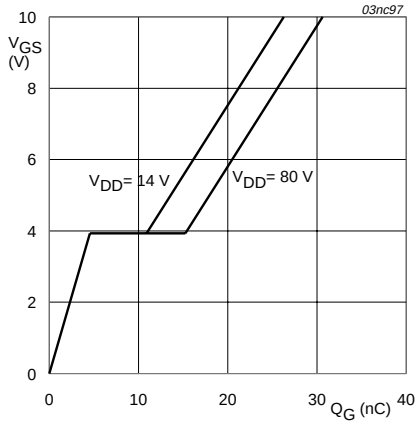


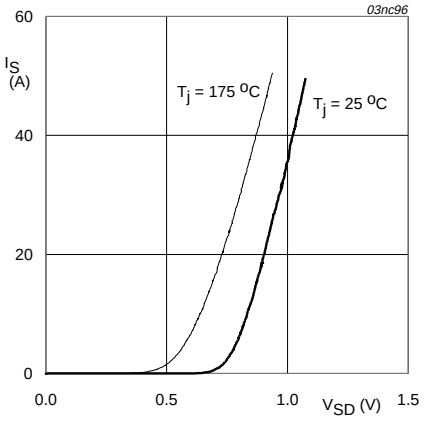
V_{DS} = 25 V

Fig 13. Transfer characteristics: drain current as a function of gate-source voltage; typical values.



T_j = 25 °C; I_D = 10 A

Fig 14. Gate-source voltage as a function of turn-on gate charge; typical values.



V_{GS} = 0 V

Fig 15. Reverse diode current as a function of reverse diode voltage; typical values.

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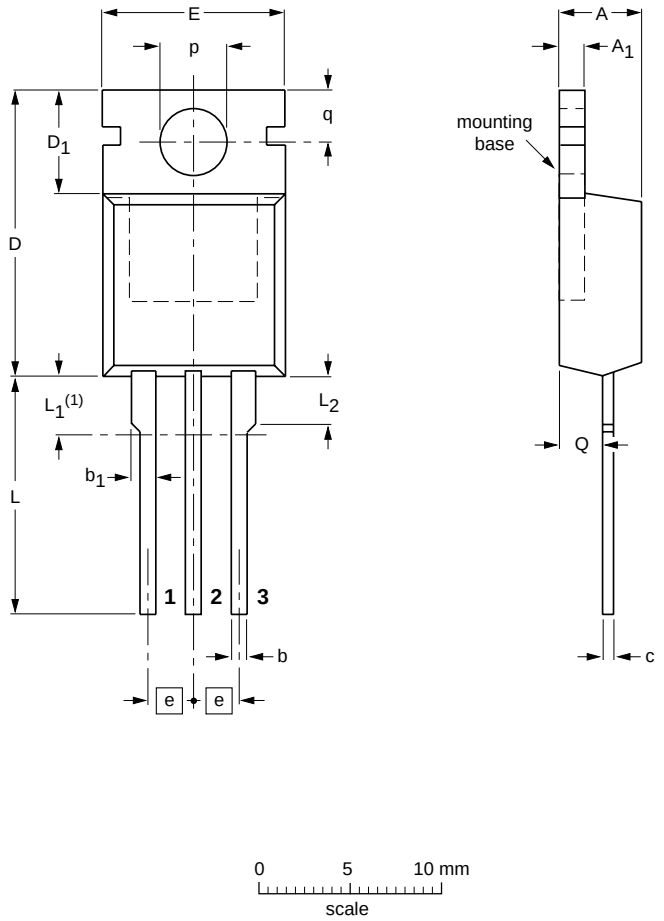
9. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB **SOT78**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1	b	b_1	c	D	D_1	E	e	L	L_1(1)	L_2 max.	p	q	Q
mm	4.5 4.1	1.39 1.27	0.9 0.7	1.3 1.0	0.7 0.4	15.8 15.2	6.4 5.9	10.3 9.7	2.54	15.0 13.5	3.30 2.79	3.0	3.8 3.6	3.0 2.7	2.6 2.2

Note

1. Terminals in this zone are not tinned.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT78		3-lead TO-220AB	SC-46			~~00-09-07~~ 01-02-16

Fig 16. SOT78 (TO-220AB).

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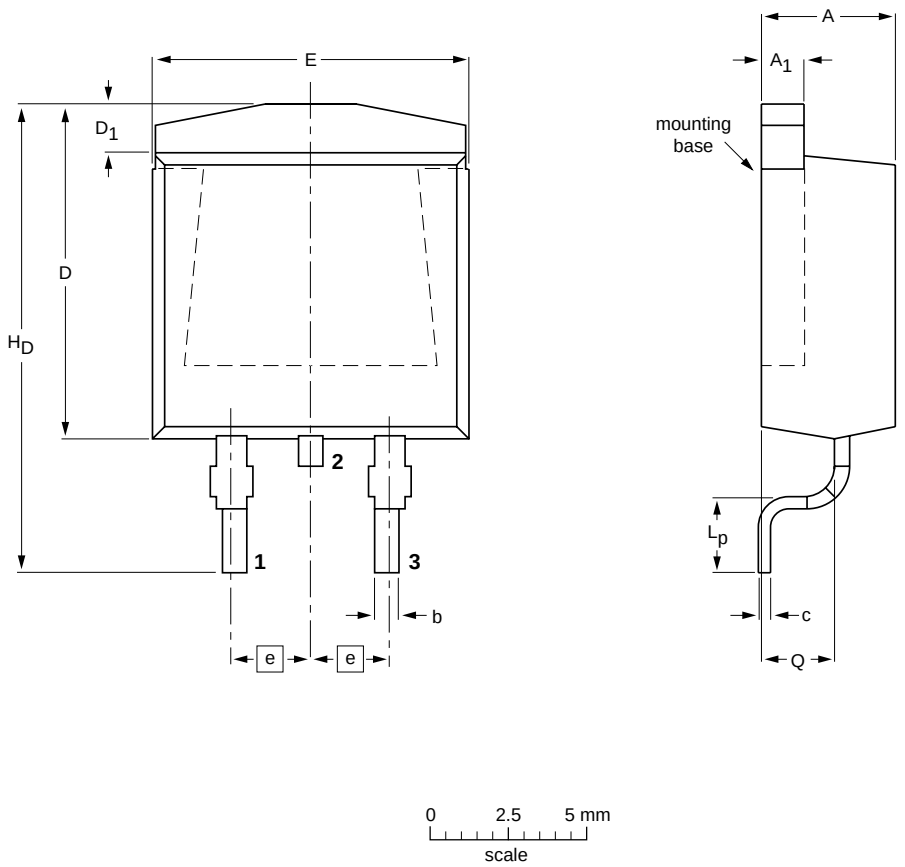
Plastic single-ended surface mounted package (Philips version of D^2-PAK); 3 leads (one lead cropped) **SOT404**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1	b	c	D max.	D_1	E	e	L_p	H_D	Q
mm	4.50 4.10	1.40 1.27	0.85 0.60	0.64 0.46	11	1.60 1.20	10.30 9.70	2.54	2.90 2.10	15.80 14.80	2.60 2.20

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT404						~~99-06-25~~ 01-02-12

Fig 17. SOT404 (D^2-PAK).

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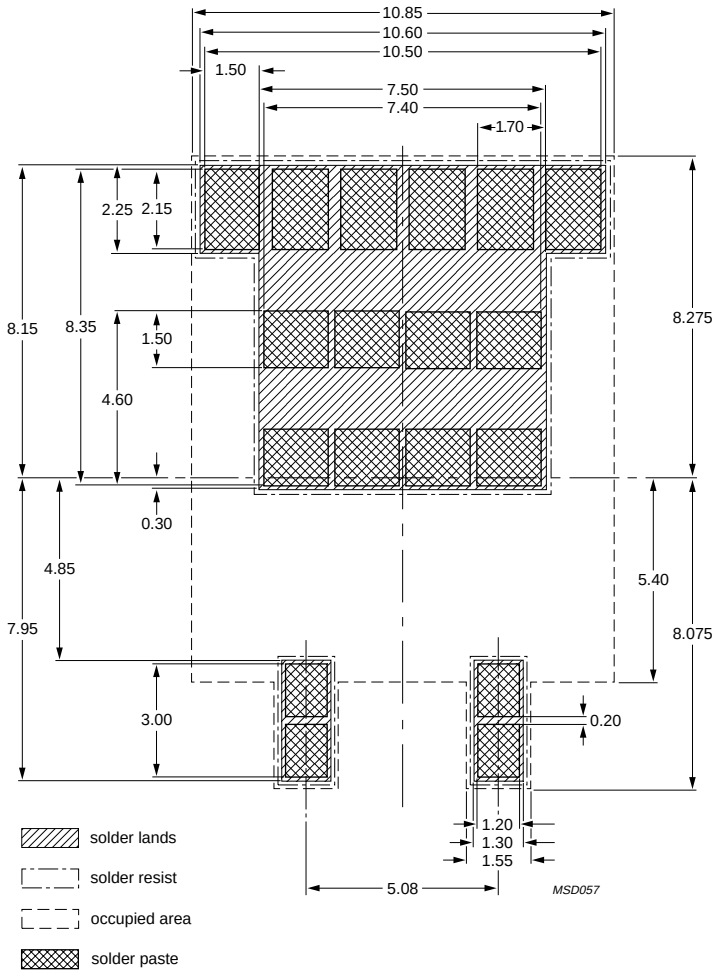
10. Soldering



Dimensions in mm.

Fig 18. Reflow soldering footprint for SOT404.

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11. Revision history

Table 6: Revision history

Rev	Date	CPCN	Description
01	20010222	-	Product specification; initial version

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12. Data sheet status

Datasheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued data sheet before initiating or completing a design.

13. Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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